

General Description

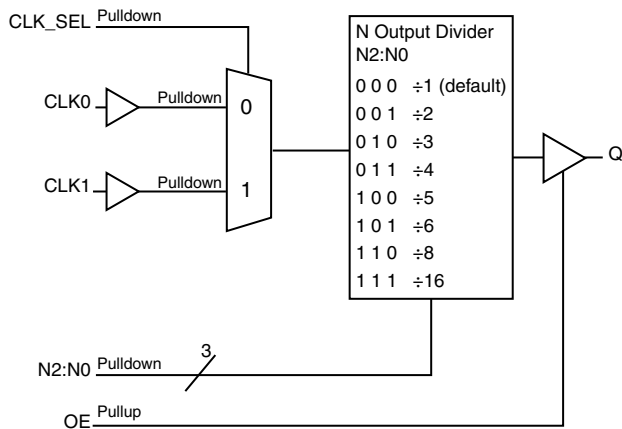
The ICS87001-01 is a low skew, $\div 1$, $\div 2$, $\div 3$, $\div 4$, $\div 5$, $\div 6$, $\div 8$, $\div 16$ LVC MOS/LVTTL Fanout Buffer/Divider. The ICS87001-01 has selectable clock inputs that accept single ended input levels. Output enable pin controls whether the output is in the active or high impedance state.

The ICS87001-01 is characterized at 3.3V, 2.5V and mixed 3.3V/2.5V, 3.3V/1.8V, 2.5V/1.8V input/output supply operating modes. Guaranteed part-to-part skew characteristics make the ICS87001-01 ideal for those applications demanding well defined performance and repeatability.

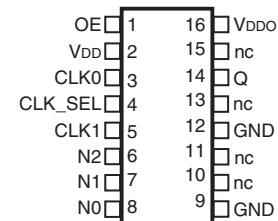
Features

- One LVC MOS / LVTTL output
- Selectable LVC MOS / LVTTL clock inputs
- Maximum output frequency: 250MHz
- Part-to-part skew: 135ps (typical)
- Power supply modes:
Core/Output
3.3V/3.3V
3.3V/2.5V
3.3V/1.8V
2.5V/2.5V
2.5V/1.8V
- 0°C to 70°C ambient operating temperature
- Lead-free (RoHS 6) packaging

Block Diagram



Pin Assignment



ICS87001-01
16-Lead TSSOP
4.4mm x 3.0mm x 0.925mm
package body
G Package
Top View

Pin Descriptions and Characteristics

Table 1. Pin Descriptions

Number	Name	Type		Description
1	OE	Input	Pullup	Output enable. When LOW, outputs are in HIGH impedance state. When HIGH, outputs are active. LVCMOS / LVTTTL interface levels.
2	V _{DD}	Power		Power supply pin.
3, 5	CLK0, CLK1	Input	Pulldown	Single-ended clock inputs. LVCMOS/LVTTTL interface levels.
4	CLK_SEL	Input	Pulldown	Input clock selection. When HIGH, selects CLK1 input. When LOW, selects CLK0 input. LVCMOS / LVTTTL interface levels.
6, 7, 8	N2, N1, N0	Input	Pulldown	Output divider select pins. LVCMOS/LVTTTL interface levels. See Table 3.
9, 12	GND	Power		Power supply ground.
10, 11, 13, 15	nc	Unused		No connect.
14	Q	Output		Single-ended clock output. LVCMOS/LVTTTL interface levels.
16	V _{DDO}	Power		Output supply pin.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
C _{PD}	Power Dissipation Capacitance	V _{DDO} = 3.465V		6		pF
		V _{DDO} = 2.625V		5		pF
		V _{DDO} = 1.95V		5		pF
R _{OUT}	Output Impedance	V _{DDO} = 3.3V±5%		17		Ω
		V _{DDO} = 2.5V±5%		20		Ω
		V _{DDO} = 1.8V±0.15V		28		Ω

Function Tables

Table 3. Programmable Output Divider Function Table

Inputs			N Divider Value	Output Frequency (MHz)
N2	N1	N0		
0	0	0	÷1 (default)	250
0	0	1	÷2	125
0	1	0	÷3	83.333
0	1	1	÷4	62.5
1	0	0	÷5	50
1	0	1	÷6	41.667
1	1	0	÷8	31.25
1	1	1	÷16	15.625

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to $V_{DD} + 0.5V$
Outputs, V_O	-0.5V to $V_{DDO} + 0.5V$
Package Thermal Impedance, θ_{JA}	100.3°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4B. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4C. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4D. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4E. Power Supply DC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4F. LVCMOS/LVTTL DC Characteristics, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	$V_{DD} = 3.3V$	2		$V_{DD} + 0.3$	V
		$V_{DD} = 2.5V$	1.7		$V_{DD} + 0.3$	V
V_{IL}	Input Low Voltage	CLK_SEL, CLK[0:1], N[2:0] $V_{DD} = 3.3V$	-0.3		0.8	V
		OE $V_{DD} = 3.3V$	-0.3		0.6	V
		CLK_SEL, CLK[0:1], N[2:0] $V_{DD} = 2.5V$	-0.3		0.7	V
		OE $V_{DD} = 2.5V$	-0.3		0.5	V
I_{IH}	Input High Current	CLK_SEL, CLK[0:1], N[2:0] $V_{DD} = V_{IN} = 3.465V$ or $2.625V$			150	μA
		OE $V_{DD} = V_{IN} = 3.465V$ or $2.625V$			5	μA
I_{IL}	Input Low Current	CLK_SEL, CLK[0:1], N[2:0] $V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-5			μA
		OE $V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$	-150			μA
V_{OH}	Output High Voltage; NOTE 1	$V_{DDO} = 3.3V$	2.6			V
		$V_{DDO} = 2.5V$	1.8			V
		$V_{DDO} = 1.8V$	1.25			V
V_{OL}	Output Low Voltage; NOTE 1	$V_{DDO} = 3.3V$			0.5	V
		$V_{DDO} = 2.5V$			0.5	V
		$V_{DDO} = 1.8V$			0.4	V
I_{OZL}	Output Hi-Z Current Low		-5			μA
I_{OZH}	Output Hi-Z Current High				5	μA

NOTE 1: Outputs terminated with 50Ω to $V_{DDO}/2$. See Parameter Measurement Information, *Output Load Test Circuit diagrams*.

AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	$N \leq 2$	3.6	4.6	5.7	ns
		$N > 2$	4.3	5.5	6.7	ns
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 2, 3				750	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.6	1.0	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f_{IN} \leq 250MHz$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	$N \leq 2$	3.5	4.8	6.2	ns
		$N > 2$	4.5	5.7	6.9	ns
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 2, 3				590	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.7	1.1	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f_{IN} \leq 250MHz$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5C. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	$N \leq 2$	3.6	5.2	7.0	ns
		$N > 2$	4.8	6.2	7.6	ns
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 2, 3				680	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	1.0	2.3	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f_{IN} \leq 250MHz$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5D. AC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ to $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	$N \leq 2$	3.7	4.9	6.2	ns
		$N > 2$	4.5	5.8	7.1	ns
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 2, 3				570	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.7	1.2	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f_{IN} \leq 250MHz$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5E. AC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, $T_A = 0^\circ\text{C}$ to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	$N \leq 2$	3.6	5.2	7.0	ns
		$N > 2$	4.8	6.2	7.7	ns
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 2, 3				550	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.5	1.1	2.5	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

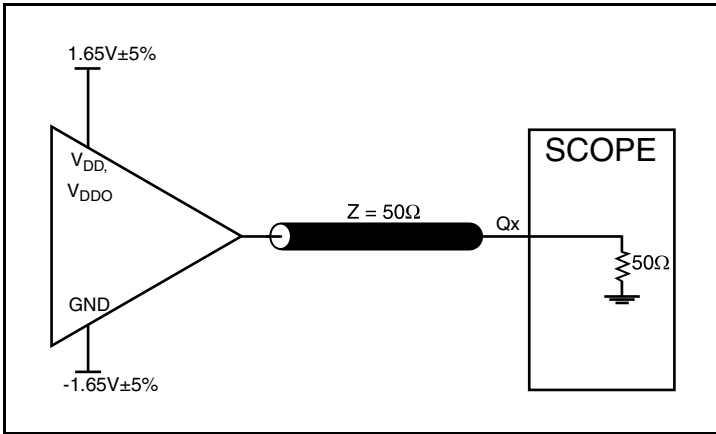
All parameters measured at $f_{IN} \leq 250\text{MHz}$ unless noted otherwise.

NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

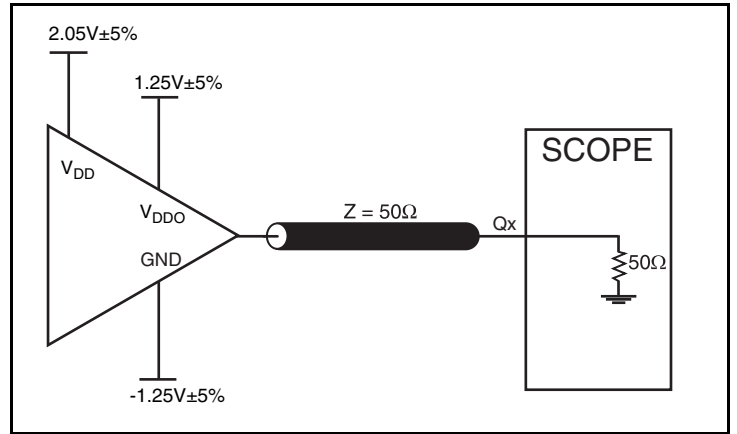
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

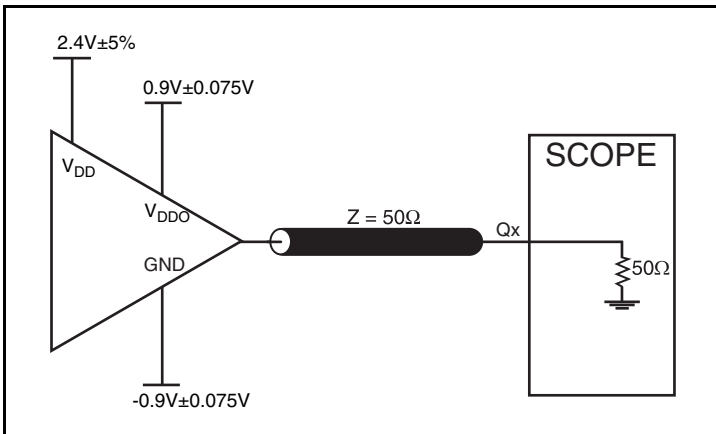
Parameter Measurement Information



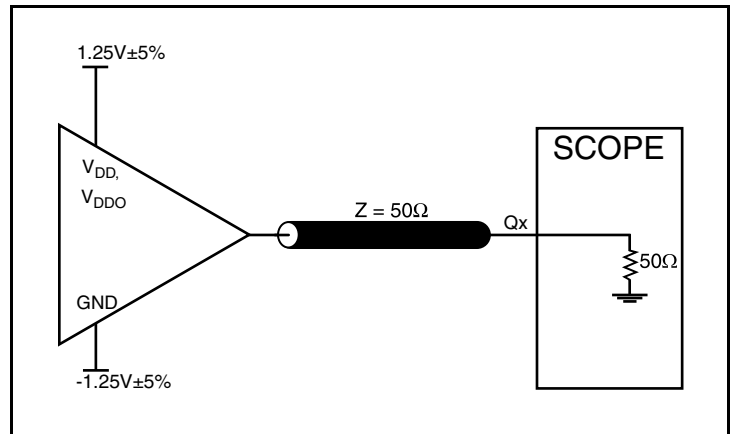
3.3V Core/3.3V LVCMOS Output Load Test Circuit



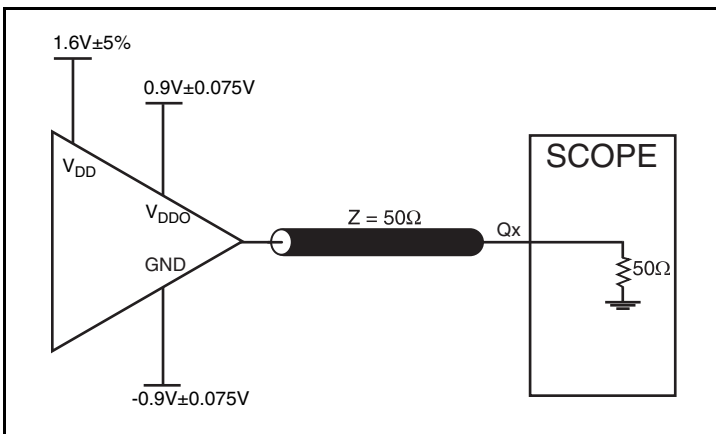
3.3V Core/2.5V LVCMOS Output Load Test Circuit



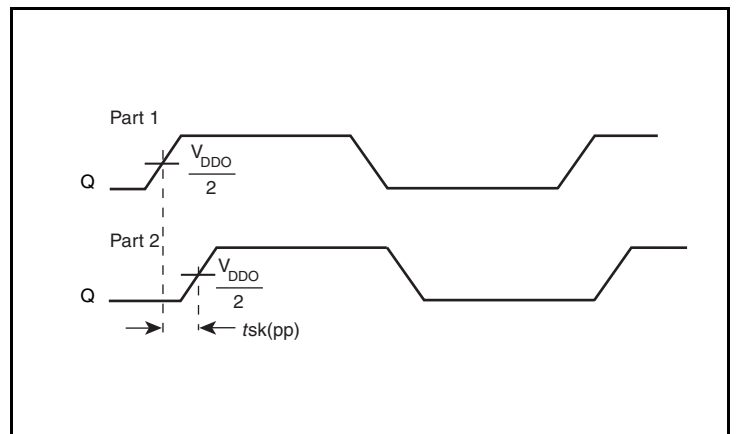
3.3V Core/1.8V LVCMOS Output Load Test Circuit



2.5V Core/2.5V LVCMOS Output Load Test Circuit

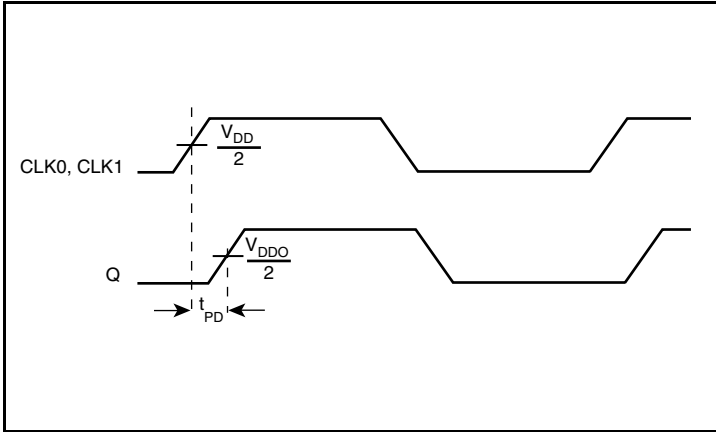


2.5V Core/1.8V LVCMOS Output Load Test Circuit

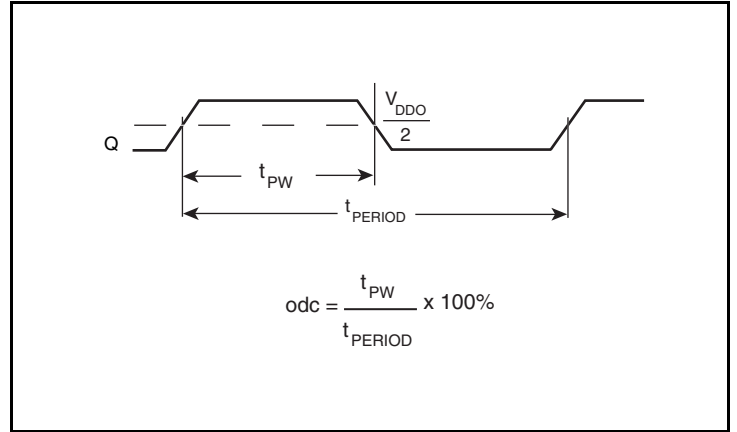


Part-to-Part Skew

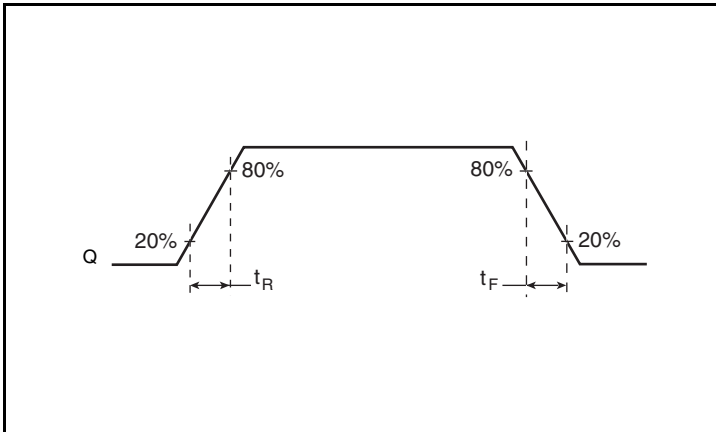
Parameter Measurement Information, continued



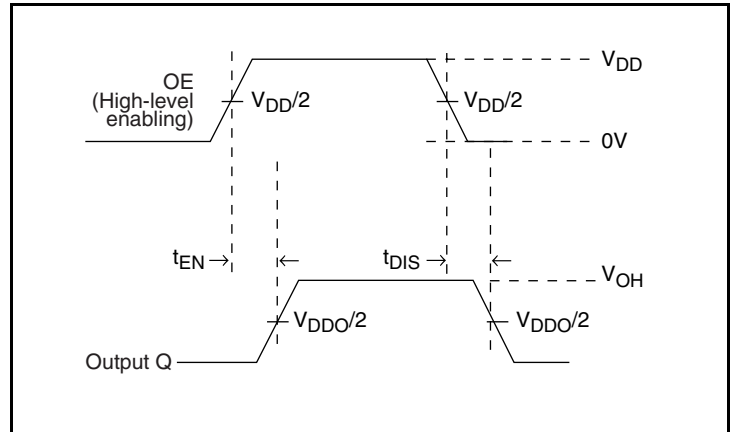
Propagation Delay



Output Duty Cycle/Pulse Width/Period



Output Rise/Fall Time



Output Enable/Disable Time

Applications Information

Recommendations for Unused Input Pins

Inputs:

LVC MOS Control Pins

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

CLK Inputs

For applications not requiring the use of a clock input, it can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from the CLK input to ground.

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS87001-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS87001-01 is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

- Power (core)_{MAX} = $V_{DD_MAX} * I_{DD} = 3.465V * 55mA = \mathbf{190.6mW}$
- Power (output)_{MAX} = $V_{DDO_MAX} * I_{DDO} = 3.465V * 5mA = 17.3mW$

LVC MOS Output Power Dissipation

- Output Impedance R_{OUT} Power Dissipation due to Loading 50Ω to $V_{DD}/2$
Output Current $I_{OUT} = V_{DD_MAX} / [2 * (50\Omega + R_{OUT})] = 3.465V / [2 * (50\Omega + 17\Omega)] = \mathbf{25.9mA}$
- Power Dissipation on the R_{OUT} per LVC MOS output
Power (R_{OUT}) = $R_{OUT} * (I_{OUT})^2 = 17\Omega * (25.9mA)^2 = \mathbf{11.4mW}$
- Total Power (R_{OUT}) = $11.4mW * 1 = \mathbf{11.4mW}$

Dynamic Power Dissipation at f_{OUT_MAX} (250MHz)

$$\text{Power (250MHz)} = C_{PD} * \text{Frequency} * (V_{DDO})^2 = 6pF * 250MHz * (3.465V)^2 = \mathbf{18mW \text{ per output}}$$

$$\text{Total Power (250MHz)} = 18mW * 1 = \mathbf{18mW}$$

Total Power Dissipation

- Total Power**
= Power (core)_{MAX} + Power (output)_{MAX} + Total Power (R_{OUT}) + Total Power (250MHz)
= $190.6mW + 17.3mW + 11.4mW + 18mW$
= $\mathbf{237.3mW}$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C . Limiting the internal transistor junction temperature, T_j , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C .

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 100.3°C/W per Table 6 below.

Therefore, T_j for an ambient temperature of 70°C with all outputs switching is:

$$70^\circ\text{C} + 0.237W * 100.3^\circ\text{C/W} = 94^\circ\text{C}. \text{ This is below the limit of } 125^\circ\text{C}.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 16 Lead TSSOP, Forced Convection

Meters per Second	θ_{JA} by Velocity		
	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	100.3°C/W	96.0°C/W	93.9°C/W

Reliability Information

Table 6. θ_{JA} vs. Air Flow Table for a 16 Lead TSSOP

θ_{JA} vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	100.3°C/W	96.0°C/W	93.9°C/W

Transistor Count

The transistor count for ICS87001-01: 2769

Package Outline and Package Dimensions

Package Outline - G Suffix for 16 Lead TSSOP

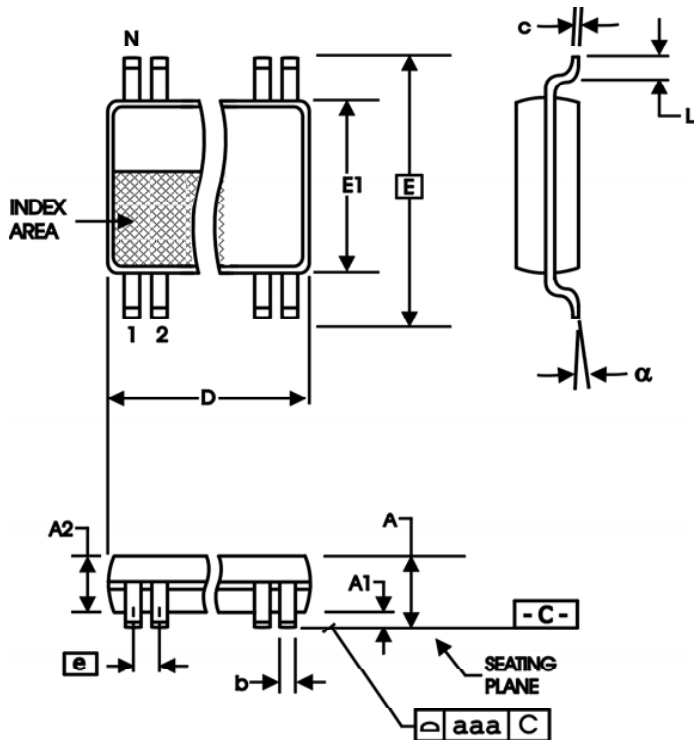


Table 7. Package Dimensions for 16 Lead TSSOP

All Dimensions in Millimeters		
Symbol	Minimum	Maximum
N	16	
A		1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
87001BG-01LF	7001B01L	"Lead-Free" 16 Lead TSSOP	Tube	0°C to 70°C
87001BG-01LFT	7001B01L	"Lead-Free" 16 Lead TSSOP	Tape & Reel	0°C to 70°C

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